



MOTOROLA
Semiconductors

BOX 20912 • PHOENIX, ARIZONA 85036

MC14011
MC14011B

QUAD 2-INPUT "NAND" GATE

The MC14011 and MC14011B are constructed with P and N channel enhancement mode devices in a single monolithic structure (Complementary MOS). Their primary use is where low power dissipation and/or high noise immunity is desired.

- Quiescent Current = 0.5 nA typ/pkg @ 5 Vdc
- Noise Immunity = 45% of V_{DD} typ
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered (MC14011B only)
- Capable of Driving Two Low-power TTL Loads, One Low-power Schottky TTL Load or Two HTL Loads Over the Rated Temperature Range. (MC14011B only)
- Double Diode Protection on All Inputs
- Pin-for-Pin Replacements for CD4011A and CD4011B

MAXIMUM RATINGS (Voltages referenced to V_{SS})

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{DD}	-0.5 to +18	Vdc
Input Voltage, All Inputs	V_{in}	-0.5 to $V_{DD} + 0.5$	Vdc
DC Current Drain per Pin	i	10	mAdc
Operating Temperature Range	T_A	-55 to +125 -40 to +85	$^{\circ}C$
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}C$

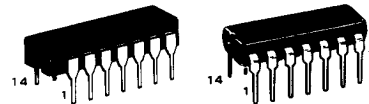
See the MC14001 data sheet for complete characteristics for the non-B device.

See the MC14001B data sheet for complete characteristics of the B-Series device.

McMOS SSI

(LOW-POWER COMPLEMENTARY MOS)

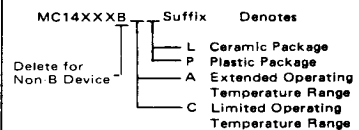
QUAD 2-INPUT "NAND" GATE



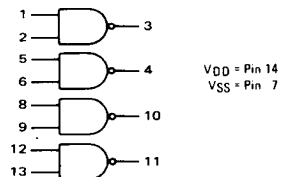
L SUFFIX
CERAMIC PACKAGE
CASE 632

P SUFFIX
PLASTIC PACKAGE
CASE 646

ORDERING INFORMATION



LOGIC DIAGRAM

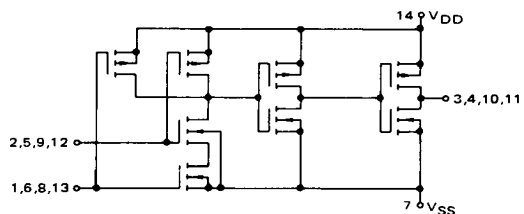
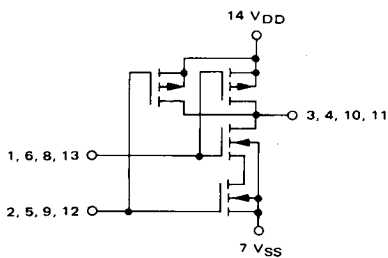


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MC14011

CIRCUIT SCHEMATICS
(1/4 of Device Shown)

MC14011B



This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields, however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit. For proper

operation it is recommended that V_{in} and V_{out} be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}).